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April 1st, 2010 Renesas Electronics Corporation

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MOS INTEGRATED CIRCUIT μ PD444016-Y

4M-BIT CMOS FAST SRAM 256K-WORD BY 16-BIT EXTENDED TEMPERATURE OPERATION

Description

The μ PD444016-Y is a high speed, low power, 4,194,304 bits (262,144 words by 16 bits) CMOS static RAM.

Operating supply voltage is 5.0 V \pm 0.5 V.

The μ PD444016-Y is packaged in 44-pin PLASTIC TSOP (II).

Features

- 262,144 words by 16 bits organization
- Fast access time: 8, 10, 12 ns (MAX.)
- Byte data control : /LB (I/O1 I/O8), /UB (I/O9 I/O16)
- Output Enable input for easy application
- Single +5.0 V power supply

Ordering Information

Part number	Package	Access time	Supply current mA (MAX.)			
		ns (MAX.)	At operating	At standby		
μPD444016G5-8Y-7JF	44-pin PLASTIC TSOP (II)	8	220	10		
μPD444016G5-10Y-7JF	(10.16 mm (400))	10	200			
μPD444016G5-12Y-7JF	(Normal bent)	12	190			
μPD444016G5-8Y-7JF-A		8	220			
μPD444016G5-10Y-7JF-A		10	200			
μPD444016G5-12Y-7JF-A		12	190			

Remark Products with -A at the end of the part number are lead-free products.

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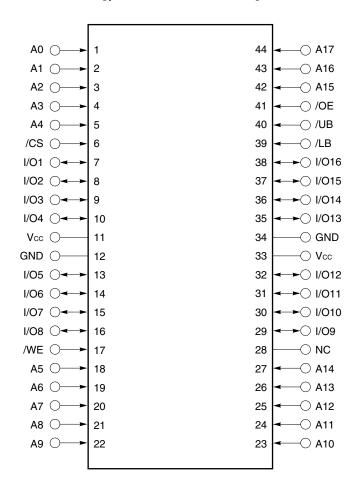
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Document No. M15391EJ3V0DS00 (3rd edition) Date Published September 2006 NS CP(K) Printed in Japan

Pin Configuration (Marking Side)

/xxx indicates active low signal.

44-pin PLASTIC TSOP (II) (10.16 mm (400)) (Normal bent)
[μPD444016G5-xxY-7JF]
[μPD444016G5-xxY-7JF-A]



A0 - A17 : Address Inputs

I/O1 - I/O16: Data Inputs / Outputs

/CS : Chip Select
/WE : Write Enable
/OE : Output Enable
/LB, /UB : Byte data select
Vcc : Power supply
GND : Ground

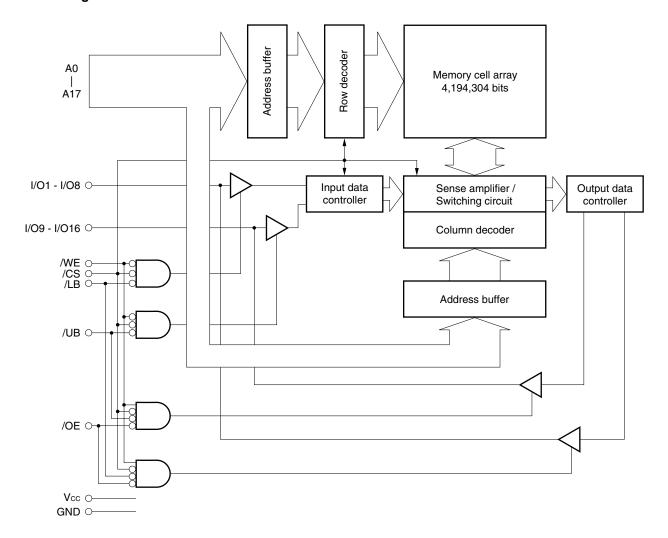
. Oround

NC : No connection

Remark Refer to Package Drawing for the 1-pin index mark.



Block Diagram



Truth Table

/CS	/OE	/WE	/LB	/UB	Mode	1/	I/O	
						I/O1 - I/O8	I/O9 - I/O16	
Н	×	×	×	×	Not selected	High impedance	High impedance	IsB
L	L	Н	L	L	Read	D оит	D оит	Icc
			L	Н		D оит	High impedance	
			Н	L		High impedance	D оит	
L	×	L	L	L	Write	Din	Din	
			L	Н		Din	High impedance	
			Н	L	High impedance Din			
L	Н	Н	×	×	Output disable	High impedance	High impedance	
L	×	×	Н	Н		High impedance	High impedance	

Remark ×: Don't care



Electrical Specifications

Absolute Maximum Ratings

Parameter	Symbol	Condition	Rating	Unit
Supply voltage	Vcc		-0.5 Note to +7.0	V
Input / Output voltage	VT		-0.5 Note to Vcc+0.5	V
Operating ambient temperature	TA		-40 to +85	°C
Storage temperature	Tstg		-55 to +125	°C

Note -2.0 V (MIN.) (pulse width: 2 ns)

Caution Exposing the device to stress above those listed in Absolute Maximum Rating could cause permanent damage. The device is not meant to be operated under conditions outside the limits described in the operational section of this specification. Exposure to Absolute Maximum Rating conditions for extended periods may affect device reliability.

Recommended Operating Conditions

Parameter	Symbol	Condition	MIN.	TYP.	MAX.	Unit
Supply voltage	Vcc		4.5	5.0	5.5	٧
High level input voltage	VIH		2.2		Vcc+0.5	V
Low level input voltage	VIL		-0.5 Note		+0.8	V
Operating ambient temperature	TA		-40		+85	°C

Note -2.0 V (MIN.) (pulse width : 2 ns)



DC Characteristics (Recommended Operating Conditions Unless Otherwise Noted)

Parameter	Symbol	Test co	ondition	MIN.	TYP.	MAX.	Unit
Input leakage current	lu	V _{IN} = 0 V to V _{CC}		-2		+2	μΑ
Output leakage current	lLO	V _{I/O} = 0 V to V _{CC} , /CS or /WE = V _{IL} or /LB =		-2		+2	μΑ
Operating supply current	Icc	/CS = V _{IL} ,	/CS = V _{IL} , Cycle time : 8 ns			220	mA
		I _{I/O} = 0 mA,	Cycle time : 10 ns			200	
		Minimum cycle time	Cycle time : 12 ns			190	
Standby supply current	IsB	/CS = VIH, VIN = VIH O	r VIL			40	mA
	ISB1	$/CS \ge Vcc - 0.2 \text{ V},$ $V_{IN} \le 0.2 \text{ V or } V_{IN} \ge V$			10		
High level output voltage	Vон	I _{OH} = -4.0 mA		2.4			V
Low level output voltage	Vol	I _{OL} = +8.0 mA				0.4	V

Remarks 1. VIN: Input voltage

VI/o : Input / Output voltage

2. These DC characteristics are in common regardless of product classification.

Capacitance (T_A = 25 °C, f = 1 MHz)

Parameter	Symbol	Test condition	MIN.	TYP.	MAX.	Unit
Input capacitance	Cin	V _{IN} = 0 V			6	pF
Input / Output capacitance	C _{I/O}	V _{I/O} = 0 V			8	pF

Remarks 1. VIN: Input voltage

V_{I/O}: Input / Output voltage

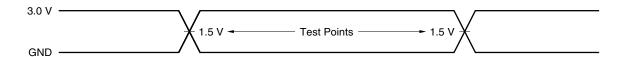
2. These parameters are not 100% tested.



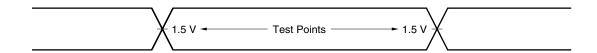
AC Characteristics (Recommended Operating Conditions Unless Otherwise Noted)

AC Test Conditions

Input Waveform (Rise and Fall Time ≤ 3 ns)



Output Waveform

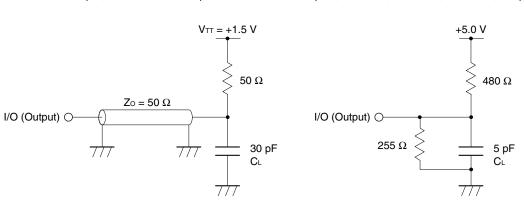


Output Load

AC characteristics directed with the note should be measured with the output load shown in **Figure 1** or **Figure 2**.

Figure 1
(taa, tacs, toe, tabd, toh)

Figure 2 (tclz, tolz, tblz, tchz, tohz, tbhz, twhz, tow)



 $\textbf{Remark} \;\; \textbf{CL} \; \text{includes capacitances of the probe and jig, and stray capacitances}.$



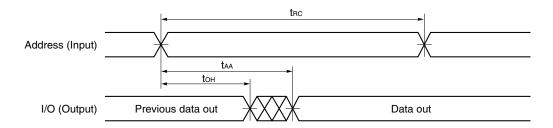
Read Cycle

Parameter	Symbol	ymbol <i>μ</i> PD444016-8Y		μPD444016-10Y		μPD444016-12Y		Unit	Notes
		MIN.	MAX.	MIN.	MAX.	MIN.	MAX.		
Read cycle time	t RC	8		10		12		ns	
Address access time	taa		8		10		12	ns	1
/CS access time	tacs		8		10		12	ns	
/OE access time	t oe		4		5		6	ns	
/LB, /UB access time	t abd		4		5		6	ns	
Output hold from address change	tон	3		3		3		ns	
/CS to output in low impedance	tclz	3		3		3		ns	2, 3
/OE to output in low impedance	tolz	0		0		0		ns	
/LB, /UB to output in low impedance	t BLZ	0		0		0		ns	
/CS to output in high impedance	tснz		4		5		6	ns	
/OE to output hold in high impedance	t onz		4		5		6	ns	
/LB, /UB to output hold in high impedance	t внz		4		5		6	ns	

Notes 1. See the output load shown in Figure 1.

- 2. Transition is measured at \pm 200 mV from steady-state voltage with the output load shown in **Figure 2**.
- 3. These parameters are not 100% tested.

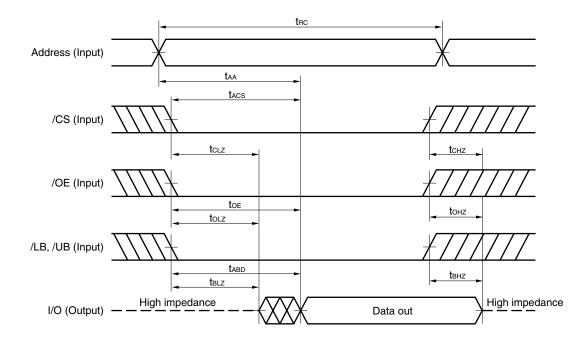
Read Cycle Timing Chart 1 (Address Access)



Remarks 1. In read cycle, /WE should be fixed to high level.

2. $/CS = /OE = /LB (or /UB) = V_{IL}$

Read Cycle Timing Chart 2 (/CS Access)



Caution Address valid prior to or coincident with /CS low level input.

Remark In read cycle, /WE should be fixed to high level.



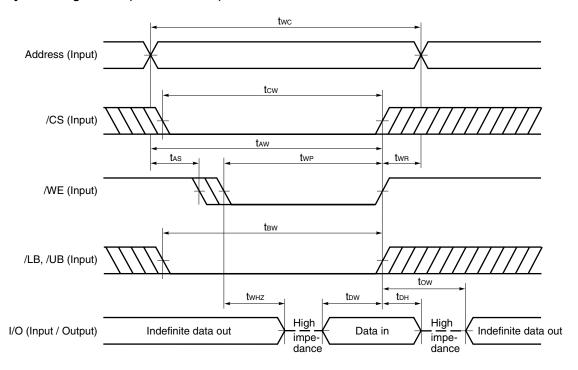
Write Cycle

Parameter	Symbol	μPD444016-8Y		μPD444016-10Y		μPD444016-12Y		Unit	Notes
		MIN.	MAX.	MIN.	MAX.	MIN.	MAX.		
Write cycle time	twc	8		10		12		ns	
/CS to end of write	tcw	6		7		8		ns	
Address valid to end of write	taw	6		7		8		ns	
Write pulse width	twp	6		7		8		ns	
/LB, /UB to end of write	tвw	6		7		8		ns	
Data valid to end of write	t _{DW}	4		5		6		ns	
Data hold time	t DH	0		0		0		ns	
Address setup time	tas	0		0		0		ns	
Write recovery time	twr	0		0		0		ns	
/WE to output in high impedance	t wnz		4		5		6	ns	1, 2
Output active from end of write	tow	3		3		3		ns	

Notes 1. Transition is measured at \pm 200 mV from steady-state voltage with the output load shown in **Figure 2**.

2. These parameters are not 100% tested.

Write Cycle Timing Chart 1 (/WE Controlled)



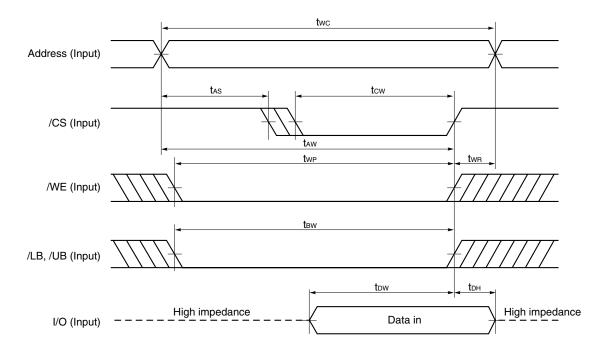
Cautions 1. /CS or /WE should be fixed to high level during address transition.

2. Do not input data to the I/O pins while they are in the output state.

Remarks 1. Write operation is done during the overlap time of a low level /CS, /LB and/or /UB, and a low level /WE.

2. When /WE is at low level, the I/O pins are always high impedance. When /WE is at high level, read operation is executed. Therefore /OE should be at high level to make the I/O pins high impedance.

Write Cycle Timing Chart 2 (/CS Controlled)

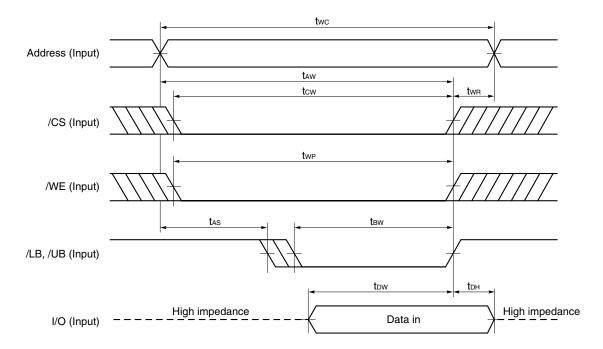


Cautions 1. /CS or /WE should be fixed to high level during address transition.

2. Do not input data to the I/O pins while they are in the output state.

Remark Write operation is done during the overlap time of a low level /CS, /LB and/or /UB, and a low level /WE.

Write Cycle Timing Chart 3 (/LB, /UB Controlled)



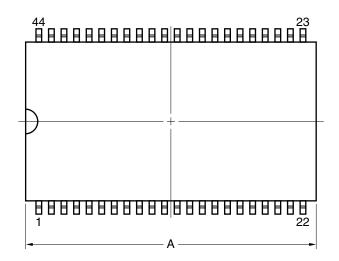
Cautions 1. /CS or /WE should be fixed to high level during address transition.

2. Do not input data to the I/O pins while they are in the output state.

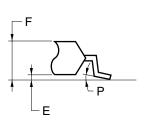
Remark Write operation is done during the overlap time of a low level /CS, /LB and/or /UB, and a low level /WE.

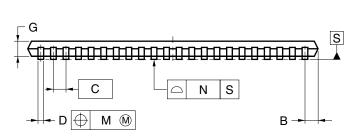
Package Drawing

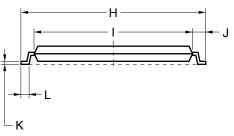
44-PIN PLASTIC TSOP (II) (10.16 mm (400))



detail of lead end







NOTE

Each lead centerline is located within 0.13 mm of its true position (T.P.) at maximum material condition.

ITEM	MILLIMETERS
A	18.63 MAX.
В	0.93 MAX.
С	0.8 (T.P.)
D	$0.32^{+0.08}_{-0.07}$
E	0.1±0.05
F	1.2 MAX.
G	0.97
Н	11.76±0.2
I	10.16±0.1
J	0.8±0.2
K	$0.145^{+0.025}_{-0.015}$
L	0.5±0.1
М	0.13
N	0.10
Р	3° ^{+7°} -3°

S44G5-80-7JF5-1

*μ*PD444016-Y



Recommended Soldering Conditions

Please consult with our sales offices for soldering conditions of the μ PD444016-Y.

Type of Surface Mount Device

 μ PD444016G5-7JF : 44-pin PLASTIC TSOP (II) (10.16 mm (400)) (Normal bent) μ PD444016G5-7JF-A : 44-pin PLASTIC TSOP (II) (10.16 mm (400)) (Normal bent)

<R> Quality Grade

- A quality grade of the products is "Standard".
- Anti-radioactive design is not implemented in the products.
- Semiconductor devices have the possibility of unexpected defects by affection of cosmic ray that reach to the ground and so forth.



Revision History

Edition/	Pa	ige	Type of	Location	Description
Date	This	Previous	revision		(Previous edition $ ightarrow$ This edition)
	edition	edition			
3rd edition/	p.13	p.13	Addition	Quality Grade	Section of Quality Grade has been added.
Sep. 2006					

NOTES FOR CMOS DEVICES —

1) VOLTAGE APPLICATION WAVEFORM AT INPUT PIN

Waveform distortion due to input noise or a reflected wave may cause malfunction. If the input of the CMOS device stays in the area between $V_{\rm IL}$ (MAX) and $V_{\rm IH}$ (MIN) due to noise, etc., the device may malfunction. Take care to prevent chattering noise from entering the device when the input level is fixed, and also in the transition period when the input level passes through the area between $V_{\rm IL}$ (MAX) and $V_{\rm IH}$ (MIN).

(2) HANDLING OF UNUSED INPUT PINS

Unconnected CMOS device inputs can be cause of malfunction. If an input pin is unconnected, it is possible that an internal input level may be generated due to noise, etc., causing malfunction. CMOS devices behave differently than Bipolar or NMOS devices. Input levels of CMOS devices must be fixed high or low by using pull-up or pull-down circuitry. Each unused pin should be connected to VDD or GND via a resistor if there is a possibility that it will be an output pin. All handling related to unused pins must be judged separately for each device and according to related specifications governing the device.

(3) PRECAUTION AGAINST ESD

A strong electric field, when exposed to a MOS device, can cause destruction of the gate oxide and ultimately degrade the device operation. Steps must be taken to stop generation of static electricity as much as possible, and quickly dissipate it when it has occurred. Environmental control must be adequate. When it is dry, a humidifier should be used. It is recommended to avoid using insulators that easily build up static electricity. Semiconductor devices must be stored and transported in an anti-static container, static shielding bag or conductive material. All test and measurement tools including work benches and floors should be grounded. The operator should be grounded using a wrist strap. Semiconductor devices must not be touched with bare hands. Similar precautions need to be taken for PW boards with mounted semiconductor devices.

4 STATUS BEFORE INITIALIZATION

Power-on does not necessarily define the initial status of a MOS device. Immediately after the power source is turned ON, devices with reset functions have not yet been initialized. Hence, power-on does not guarantee output pin levels, I/O settings or contents of registers. A device is not initialized until the reset signal is received. A reset operation must be executed immediately after power-on for devices with reset functions.

(5) POWER ON/OFF SEQUENCE

In the case of a device that uses different power supplies for the internal operation and external interface, as a rule, switch on the external power supply after switching on the internal power supply. When switching the power supply off, as a rule, switch off the external power supply and then the internal power supply. Use of the reverse power on/off sequences may result in the application of an overvoltage to the internal elements of the device, causing malfunction and degradation of internal elements due to the passage of an abnormal current.

The correct power on/off sequence must be judged separately for each device and according to related specifications governing the device.

(6) INPUT OF SIGNAL DURING POWER OFF STATE

Do not input signals or an I/O pull-up power supply while the device is not powered. The current injection that results from input of such a signal or I/O pull-up power supply may cause malfunction and the abnormal current that passes in the device at this time may cause degradation of internal elements. Input of signals during the power off state must be judged separately for each device and according to related specifications governing the device.

*μ*PD444016-Y

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